Application No.: 09/780,390 Docket No.: M4065.0111/P111-A

Amendment dated July 22, 2004

Reply to Office action dated May 24, 2004

AMENDMENTS TO THE SPECIFICAITON

On the cover page and page 1, please replace the title with the following:

OPTIMIZED-LOW LEAKAGE DIODES, INCLUDING PHOTODIODES

On page 13, please replace the paragraph beginning on line 9 with the

following:

For the photodiode 215 of the secondthird embodiment, the processing is

essentially complete at this stage, and conventional processing methods may then be

used to form contacts and wiring to connect the photodiode 215 to an imager

apparatus. For example, the entire surface of the photodiode may then be covered with

a passivation layer of, e.g., silicon dioxide or BPSG, which is CMP planarized and

etched to provide contact holes, which are then metallized to provide contacts to the

photodiode 215.

On page 14, please replace the paragraph beginning on line 9 with the

following:

For the photodiode 215 of the second third embodiment, the processing is

essentially complete at this stage, and conventional processing methods may then be

used to form contacts and wiring to connect the photodiode 215 to an imager apparatus

as described in more detail above.

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